



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of: }
Fastow et al. } Examiner: NGUYEN, D.
Serial No.: 10/658,936 } Art Unit: 2818
Filed: September 9, 2003 } Confirmation No.: 3102
For: FLASH MEMORY WITH }
HIGH-K DIELECTRIC }
MATERIAL BETWEEN }
SUBSTRATE AND GATE }

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE TO OFFICE ACTION

Dear Sir:

In response to the Office Action mailed January 23, 2007, please consider the following remarks. The claims are presented beginning on page 2 of this response.

Remarks begin on page 6.